Supporting Information

Iridium-based Emitters Containing Pendant Triphenylene Moieties for Blue Green OLEDs with Improved Efficiency upon Thermal Annealing

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Figure S1. TGA curves (a) and DSC curves (b) of iridium complexes



Figure S2. Luminescent images of YF3 and YF4 under UV light with 365 nm excitation



Figure S3. Figure PL profiles of YF-3 measured before and after annealing





Figure S4. CV curves of YF3 and YF4 measured in CH_2Cl_2 with a scan rate of 100 mV/s (inset: Fc/Fc⁺ curve)





Figure S5. EQE-Current density curves of YF3 and YF4-based devices recorded at 10 V





Figure S6. Power efficiency-Current density curves of YF3 and YF4-based devices recorded at 10 V

NMR spectra

















¹³C NMR spectrum of compound IrYF4